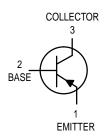
# **Amplifier Transistors PNP Silicon**



## **MAXIMUM RATINGS**

Rating	Symbol	2N5400	2N5401	Unit		
Collector-Emitter Voltage	VCEO	120	150	Vdc		
Collector-Base Voltage	V <sub>CBO</sub>	130	160	Vdc		
Emitter-Base Voltage	VEBO	5.0		Vdc		
Collector Current — Continuous	IC	600		mAdc		
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	625 5.0		mW mW/°C		
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	1.5 12				Watts mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150		°C		

# THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{ heta JC}$	83.3	°C/W

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteris	stic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage <sup>(1)</sup> (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	2N5400 2N5401	V(BR)CEO	120 150	_	Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = 100 μAdc, I <sub>E</sub> = 0)	2N5400 2N5401	V <sub>(BR)</sub> CBO	130 160	_ _	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10 \mu Adc, I_C = 0$ )		V(BR)EBO	5.0	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 100 Vdc, I <sub>E</sub> = 0) (V <sub>CB</sub> = 120 Vdc, I <sub>E</sub> = 0) (V <sub>CB</sub> = 100 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 100°C) (V <sub>CB</sub> = 120 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 100°C)	2N5400 2N5401 2N5400 2N5401	ICBO	_ _ _ _	100 50 100 50	nAdc μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 3.0 Vdc, I <sub>C</sub> = 0)		I <sub>EBO</sub>	_	50	nAdc

<sup>1.</sup> Pulse Test: Pulse Width =  $300 \mu s$ , Duty Cycle = 2.0%.

Preferred devices are Motorola recommended choices for future use and best overall value.

# 2N5400 2N5401\*

\*Motorola Preferred Device





# 2N5400 2N5401

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Max	Unit
ON CHARACTERISTICS(1)					
DC Current Gain (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 5.0 Vdc)	2N5400 2N5401	hFE	30 50	_	_
(I <sub>C</sub> = 10 mAdc, $V_{CE}$ = 5.0 Vdc)	2N5400 2N5401		40 60	180 240	
$(I_C = 50 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	2N5400 2N5401		40 50	_ _	
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 1.0 mAdc) (I <sub>C</sub> = 50 mAdc, I <sub>B</sub> = 5.0 mAdc)		VCE(sat)		0.2 0.5	Vdc
Base-Emitter Saturation Voltage (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 1.0 mAdc) (I <sub>C</sub> = 50 mAdc, I <sub>B</sub> = 5.0 mAdc)		V <sub>BE</sub> (sat)	_ _	1.0 1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					-
Current-Gain — Bandwidth Product (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 100 MHz)	2N5400 2N5401	fΤ	100 100	400 300	MHz
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)		C <sub>obo</sub>	_	6.0	pF
Small–Signal Current Gain (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	2N5400 2N5401	h <sub>fe</sub>	30 40	200 200	_
Noise Figure (IC = 250 $\mu$ Adc, VCE = 5.0 Vdc, RS = 1.0 k $\Omega$ , f = 1.0 kHz)		NF	_	8.0	dB

<sup>1.</sup> Pulse Test: Pulse Width =  $300 \mu s$ , Duty Cycle = 2.0%.

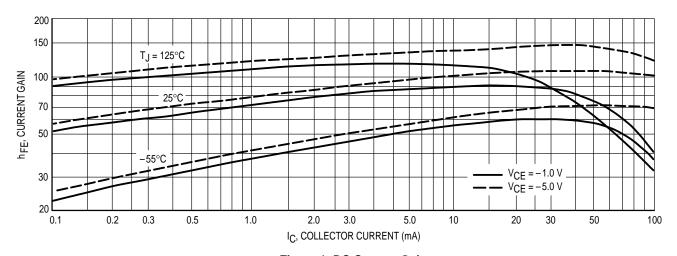


Figure 1. DC Current Gain

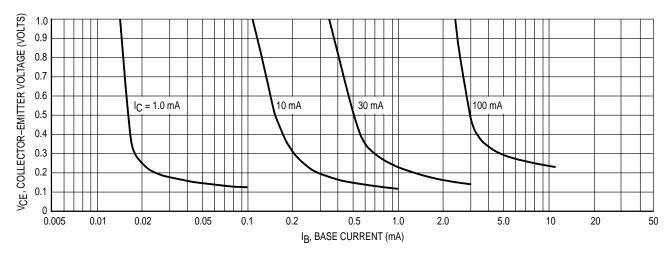


Figure 2. Collector Saturation Region

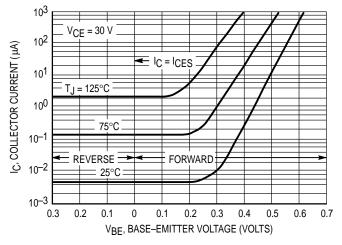


Figure 3. Collector Cut-Off Region

### 2N5400 2N5401

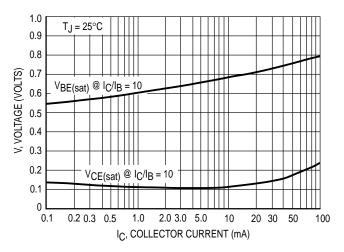


Figure 4. "On" Voltages

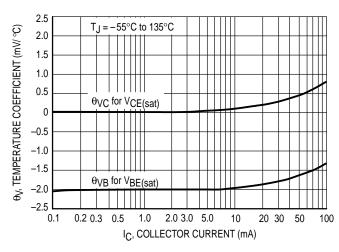
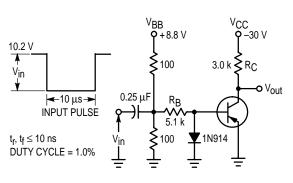


Figure 5. Temperature Coefficients



Values Shown are for I<sub>C</sub> @ 10 mA

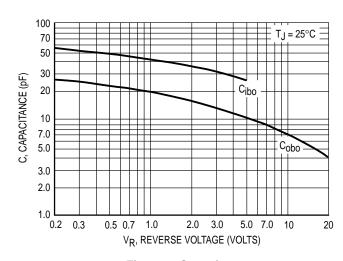
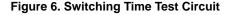


Figure 7. Capacitances



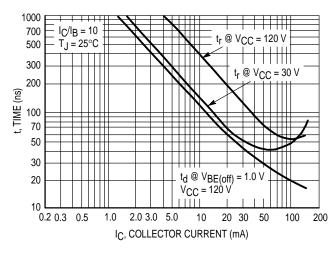


Figure 8. Turn-On Time

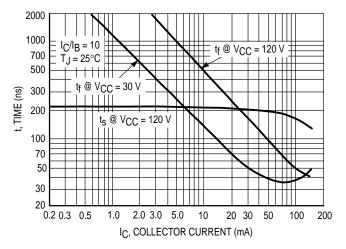
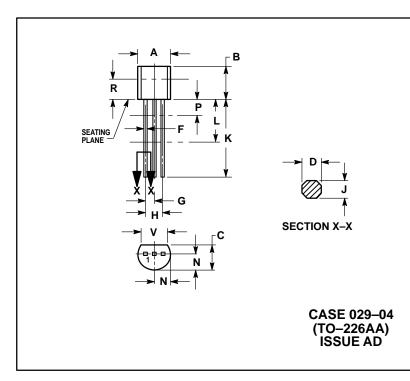


Figure 9. Turn-Off Time

# **PACKAGE DIMENSIONS**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTROLLING PERCHAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION DAND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
V	0.135		3 43	

STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

#### 2N5400 2N5401

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